NSN 5961-00-027-8110

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-027-8110 **Inclosure Material:** Metal **Overall Length:** 0.405 inches **Overall Diameter:** 0.424 inches **Mounting Facility Quantity: Mounting Method:** Threaded stud Features Provided: Hermetically sealed case **Overall Width Across Flats:** Between 0.424 inches and 0.427 inches **Thread Size:** 0.190 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 22.0 regulator voltage **Current Rating Per Characteristic:** 30.00 milliamperes repetitive peak forward current **Power Rating Per Characteristic:** 3.5 watts total power dissipation **Thread Series Designator:** Unf **Terminal Type And Quantity:** 1 threaded stud and 1 tab, solder lug **Specification Data:** 80131-release2547 professional/industrial association specification Shelf Life: N/a **Unit Of Measure: Demilitarization:**

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